HAMAMATSU

PHOTOMULTIPLIER TUBES R7447 R7447P (For Photon Counting)

Very High Cathode Sensitivity with Low Noise Photocathode

FEATURES

Spectral Response	160 to 710 nm
● High Cathode Sensitivity	
Luminous	100 μ A/lm
Radiant at 410nm	70 mA/W
●High Anode Sensitivity (at 1000V)	
Luminous	1200A/lm
Radiant at 410nm	8.4 \times 10 ⁵ A/W
Low Dark Current	0.2nA
Low Dark Counts (R7447P)	10 cps

APPLICATIONS

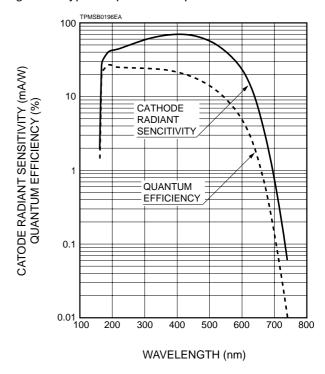
- Environmental Monitoring
- Atomic Emission Spectrometer
- Atomic Absorption Spectrometer



GENERAL

Parameter	Description/Value	Unit
Spectral Response	160 to 710	nm
Wavelength of Maximum Response	410	nm
Photocathode Material Minimum Effective Area	Low noise bialkali 8 × 24	– mm
Window Material	Fused Silica	_
Dynode Secondary Emitting Surface Structure Number of Stages	Low noise bialkali Circular-cage 9	
Direct Interelectrode Capacitances Anode to Last Dynode Anode to All Other Electrodes	4	pF pF
Base	11-pin base JEDEC No. B11-88	_
Weight	45	g
Suitable Socket	E678-11A (option)	_
Suitable Socket Assembly	E717-63 (option)	_

Figure 1: Typical Spectral Response



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MAXIMUM RATINGS (Absolute Maximum Values)

Parameter	Value	Unit		
Supply Voltage				
Between Anode and Cathode	1250	Vdc		
Between Anode and Last Dynode	250	Vdc		
Average Anode Current ^A	0.1	mA		

CHARACTERISTICS (at 25 °C)	for 0	R7447 Seneral Pur	oose	for F	R7447P Photon Coul		
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Cathode Sensitivity Quantum Efficiency at 300nm Luminous B Radiant at 410nm (Peak) Blue ^C Anode Sensitivity	80 —	24 100 70 8	_ _ _	- 80 - -	24 100 70 8	_ _ _	% μΑ/lm mΑ/W μΑ/lm-b
Luminous ^D Radiant at 400nm	1000	1200 8.4 × 10 ⁵		1000	1200 8.4 × 10 ⁵		A/lm A/W
Gain ^E Anode Dark Current ^F After 30minutes Storage in the darkness Anode Dark Counts ^F		1.2 × 10 ⁷ 0.2 —	2.0		1.2 × 10 ⁷ 0.2 10	0.5 50	nA cps
ENI(Equivalent Noise Input) ^G Time Response ^D Anode Pulse Rise Time ^H Electron Transit Time ^J Transit Time Spread (TTS) ^K	_ _ _	3.30 × 10 ⁻¹⁷ 2.2 22 1.2		_ _ _	3.30 × 10 ⁻¹⁷ 2.2 22 1.2		W ns ns ns
Anode Current Stability ^L Current Hysteresis Voltage Hysteresis	_	0.1 1.0	_	_	0.1 1.0	_	% %

NOTES

- A: Averaged over any interval of 30 seconds maximum.
- B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856K. Supply voltage is 150 volts between the cathode and all other electrodes connected together as anode.
- C:The value is cathode output current when a blue filter(Corning CS-5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note B.
- D: Measured with the same light source as Note B and with the anode-tocathode supply voltage and voltage distribution ratio shown in Table 1 below
- E: Measured with the same supply voltage and voltage distribution ratio as Note D after removal of light.
- F: Measured at the voltage producing the gain of 1×10^6 .
- G:ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot ldb \cdot G \cdot f}}{s}$$

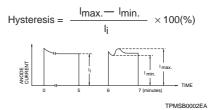
where $q = Electronic charge (1.60 \times 10^{-19} coulomb)$.

ldb = Anode dark current(after 30 minute storage) in amperes.

G = Gain.

- f = Bandwidth of the system in hertz. 1 hertz is used.
- S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.
- H:The rise time is the time for the output pulse to rise from 10% to 90% of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- J: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.

- K: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.
- L: Hysteresis is temporary instability in anode current after light and voltage are applied.



(1)Current Hysteresis

The tube is operated at 750 volts with an anode current of 1 micro-ampere for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation.

(2)Voltage Hysteresis

The tube is operated at 300 volts with an anode current of 0.1 micro-ampere for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 volts. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.

Table 1:Voltage Distribution Ratio

	-																
Electrodes	k	(Dy1	Dy	/2	Dy3	Dy	4 D	у5	Dy	6 D	у7	Dy	8 D	у9		Р
Distribution Ratio		1		1	1		1	1	,	1	1	1	ı	1		1	

Supply Voltage: 1000Vdc

K: Cathode, Dy: Dynode, P: Anode

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Figure 2: Typical Gain and Anode Dark Current

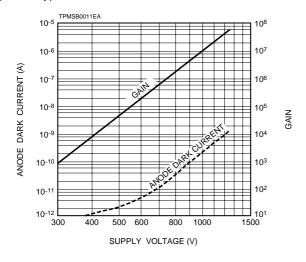


Figure 4: Typical ENI vs. Wavelength

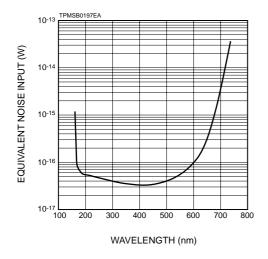


Figure 6: Typical Single Photon Pulse Height Distribution for R7447P

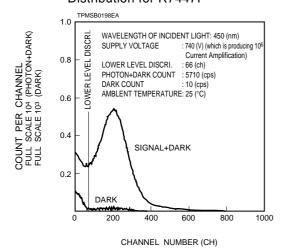


Figure 3: Typical Time Response

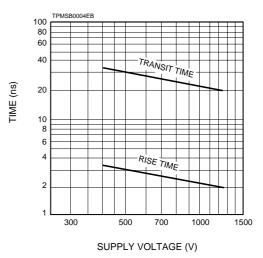
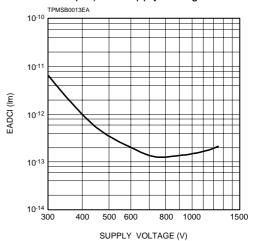
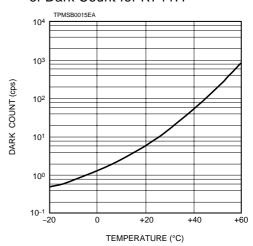


Figure 5: Typical EADCI (Equivalent Anode Dark Current Input) vs. Supply Voltage



Data shown here, which is given from a relation among supply voltage, anode sensitivity and dark current, serves as a good reference in order to determine the most suitable supply voltage or its range.

Figure 7: Typical Temperature Characteristics of Dark Count for R7447P



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Figure 8: Dimensional Outline and Basing Diagram(Unit: mm) Figure 10: Socket E678-11A (Option)

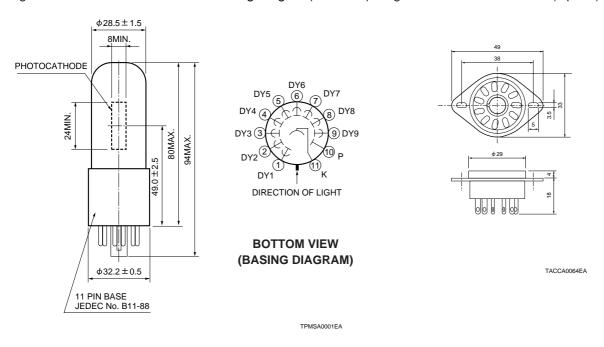
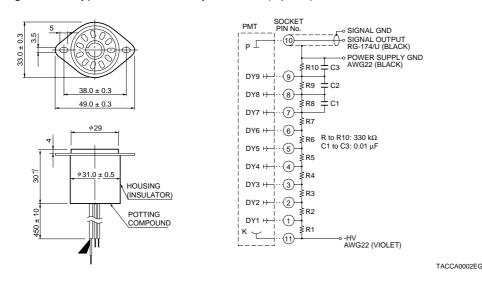


Figure 9: D Type Socket Assembly E717-63 (Option)



* Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

Warning-Personal Safety Hazards

Electrical Shock–Operating voltages applied to this device present a shock hazard.

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HOMEPAGE URL http://www.hamamatsu.com

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